# 3.3V, Wide Bandwidth, 8-Channel, 2:1 Mux/DeMux USB 2.0 Switch with Single Enable 

## Features

- $\mathrm{R}_{\mathrm{ON}}$ is $4 \Omega$ typical
- Low bit-to-bit skew: 200ps
- Low crosstalk: -27 dB @ 250 MHz
- Low Current Consumption; 20 2 A
- Near-Zero propagation delay: 250ps
- Switching speed: 3ns
- Channel On-Capacitance: 6pF (typical)
- $\mathrm{V}_{\mathrm{CC}}$ Operating Range: +3.0 V to +3.6 V
- ESD $>2000 \mathrm{~V}$. . . Human Body Model
- $>500 \mathrm{MHz}$ bandwidth (or data frequency)
- Packaging (Pb-free \& Green available):
-48-pin 240 mil wide plastic TSSOP (A)


## Applications

- Routes physical layer signals for high-speed, high bandwidth differential protocols


## Block Diagram



## Description

The PI3USB40 is a 16 - to 8 -channel multiplexer/demultiplexer Switch with Hi-Z outputs. Industry leading advantages include a propagation delay of less than 250 ps , resulting from its low channel resistance and I/O capacitance. The device multiplexes differential outputs from a USB transceiver device to one of two corresponding outputs.

The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. It is designed for low bit-to-bit skew, high channel-to-channel noise isolation and is compatible with various standards, such as High Speed USB 2.0 ( $480 \mathrm{Mb} / \mathrm{s}$ ).

## Pin Description

| $V _ { D D } \longdiv { 1 }$ | 48 019 |
| :---: | :---: |
| Yo 2 | $47{ }_{11}{ }_{1}$ |
| GND 3 | $46 \square$ GND |
| $Y_{1}{ }^{\text {d }}$ | $45 \mathrm{Ol}_{2}$ |
| GND 5 | $44{ }_{1} 12$ |
| VDD 6 | $43 \sim$ GND |
| GND 4 | $42{ }_{21}$ |
| $Y_{2} 8$ | $41{ }_{31}$ |
| GND 9 | $40 \sim$ GND |
| $\mathrm{Y}_{3}$ | $39{ }^{2}{ }^{12}$ |
| GND 11 | $38{ }_{312}$ |
| VDD 12 | 37 G GND |
| GND 13 | $36 V_{D D}$ |
| NC 14 | $35{ }_{41}$ |
| $\mathrm{Y}_{4} 15$ | $34{ }_{511}$ |
| GND 16 | $33 \sim$ GND |
| Y5 17 | $32{ }_{4}{ }^{12}$ |
| GND 18 | $31{ }^{1}{ }^{1}$ |
| VDD 19 | $30 \sim$ GND |
| GND 20 | $29{ }_{6}{ }_{11}$ |
| Y6 21 | $28{ }_{71}$ |
| GND 22 | 27 GND |
| $\mathrm{Y}_{7} \mathrm{C}_{2}$ | $26{ }_{6}{ }^{12}$ |
| SEL 24 | $25{ }_{7 \mathrm{l}_{2}}$ |

## Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

$$
\begin{aligned}
& \text { Storage Temperature.................................... }-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C} \\
& \text { Supply Voltage to Ground Potential................ }-0.5 \mathrm{~V} \text { to }+4.0 \mathrm{~V} \\
& \text { DC Input Voltage...................................................................................................................................................................................... }
\end{aligned}
$$

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Truth Table

| Function | SEL |
| :---: | :---: |
| $\mathrm{Y}_{\mathrm{N}}$ to $\mathrm{N}_{1}$ | L |
| $\mathrm{Y}_{\mathrm{N}}$ to $\mathrm{N}_{2}$ | H |

DC Electrical Characteristics for USB 2.0 Switching over Operating Range
( $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Paramenter | Description | Test Conditions | Min. | Typ. ${ }^{(2)}$ | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage | Guaranteed HIGH level | 2 |  |  | V |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage | Guaranteed LOW level |  |  | 0.8 |  |
| $\mathrm{V}_{\text {IK }}$ | Clamp Diode Voltage | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{I}_{\text {IN }}=-18 \mathrm{~mA}$ |  | $-0.7$ | -1.2 |  |
| $\mathrm{I}_{\mathrm{IH}}$ | Input HIGH Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ |  |  | $\pm 5$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IL }}$ | Input LOW Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{GND}$ |  |  | $\pm 5$ |  |
| IofF | Power Down Leakage Current | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{B}} \leq 3.6$ |  |  |  |  |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch On-Resistance(3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\text { Min., } 1.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{IN}} \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ |  | 4 | 8 | $\Omega$ |
| $\mathrm{R}_{\mathrm{FLAT}}(\mathrm{ON})$ | On-Resistance Flatness(4) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\text { Min., } \mathrm{V}_{\mathrm{IN}} @ 1.5 \mathrm{~V} \text { and } \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ |  | 1 |  |  |
| $\Delta \mathrm{R}_{\mathrm{ON}}$ | On-Resistance match from center ports to any other port $(4)$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\text { Min., } 1.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{IN}} \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ |  | 0.9 | 2 |  |

Capacitance $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}\right)$

| Parameters ${ }^{(5)}$ | Description | Test Conditions | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}$ | 2.0 | 3.0 | pF |
| Coff | Port I Capacitance, Switch OFF |  | 4.0 | 6.0 |  |
| CON | Switch Capacitance, Switch ON |  | 6.0 | 10.0 |  |

## Notes:

1. For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ambient and maximum loading.
3. Measured by the voltage drop between $A$ and $B$ pins at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (A \& B) pins.
4. This parameter is determined by device characterization but is not production tested.

## Power Supply Characteristics

| Parameters | Description | Test Conditions ${ }^{(\mathbf{1 )}}$ | Min. | Typ. ${ }^{(\mathbf{2})}$ | Max. | Units |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent Power Supply Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\mathrm{IN}}=\mathrm{GND}$ or $\mathrm{V}_{\mathrm{CC}}$ |  |  | 800 | $\mu \mathrm{~A}$ |

Notes:

1. For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ambient and maximum loading.
3. Per TTL driven input (control inputs only); A and $B$ pins do not contribute to $\mathrm{I}_{\mathrm{CC}}$.

## Dynamic Electrical Characteristics Over the Operating Range ( $\mathrm{T}_{\mathrm{A}}=-40^{\circ}$ to $+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%, \mathrm{GND}=0 \mathrm{~V}$ )

| Parameter | Description | Test Conditions | Min. | Typ. ${ }^{(2)}$ | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | $\mathrm{R}_{\mathrm{L}}=100 \Omega, \mathrm{f}=250 \mathrm{MHz}$ |  | -27 |  | dB |
| O IRR | OFF Isolation |  |  | -32 |  |  |
| BW | Bandwidth -3dB | $\mathrm{R}_{\mathrm{L}}=100 \Omega$ |  | 500 |  | MHz |

## Switching Characteristics

| Paramenter | Description | Test <br> Conditions | Min. | Typ. ${ }^{(2)}$ | Max. | Units |
| :--- | :--- | :--- | :--- | :---: | :---: | :---: |
| tPD | Propagation Delay(2,3) |  |  | 0.25 |  |  |
| tPZH, tPZL | Line Enable Time - SEL to YN, IN |  | 0.5 |  | 15 |  |
| tPHZ, tPLZ | Line Disable Time - SEL to YN, IN |  | 0.5 |  | 9 |  |
| tSK(o) | Output Skew between center port (Y4 to Y5) to any other port(2) |  |  | 0.1 | 0.2 |  |
| tSK(p) | Skew between opposite transitions of the same output (tPHL <br> - tPLH) (2) |  |  | 0.1 | 0.2 |  |

## Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Guaranteed by design.
3. The bus switch contributes no propagational delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 10 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.

## Test Circuit for Electrical Characteristics ${ }^{(1)}$



Notes:

1. $\quad \mathrm{C}_{\mathrm{L}}=$ Load capacitance: includes jig and probe capacitance.
2. $\quad \mathrm{R}_{\mathrm{T}}=$ Termination resistance: should be equal to $\mathrm{Z}_{\mathrm{OUT}}$ of the Pulse Generator
3. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
4. All input impulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$, $\mathrm{t}_{\mathrm{R}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{F}} \leq 2.5 \mathrm{~ns}$.
5. The outputs are measured one at a time with one transition per measurement.

## Switch Positions

| Test | Switch |
| :---: | :---: |
| t PLZ, tPZL (output on B-side) | 6.0 V |
| $\mathrm{t}_{\text {PHZ, }}$ tPZH (output on B-side) | GND |
| Prop Delay | Open |

## Test Circuit for Dynamic Electrical Characteristics



## Switching Waveforms



Voltage Waveforms Propagation Delay Times


Output Skew - $\mathbf{t}_{\text {SK(0) }}$


Voltage Waveforms Enable and Disable Times


Pulse Skew - $\mathbf{t s K}_{\text {SK }}$ (p)

## Applications Information

## Logic Inputs

The logic control inputs can be driven up to +3.6 V regardless of the supply voltage. For example, given a +3.3 V supply, the output enables or select pins may be driven low to 0 V and high to 3.6 V . Driving IN Rail-to-Rail $\mathbb{R}$ minimizes power consumption.
Power-Supply Sequencing
Proper power-supply sequencing is advised for all CMOS devices. It is recommended to always apply $\mathrm{V}_{\mathrm{CC}}$ before applying signals to the input/output or control pins.
Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd

## Packaging Mechanical: 48-Pin TSSOP (A)



Ordering Information

| Ordering Code | Package Code | Package Description |
| :---: | :---: | :--- |
| PI3USB40A | A | 48-pin 240 mil wide plastic TSSOP |
| PI3USB40AE | A | Pb-free \& Green, 48-pin 240 mil wide plastic TSSOP |

Notes:

1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
